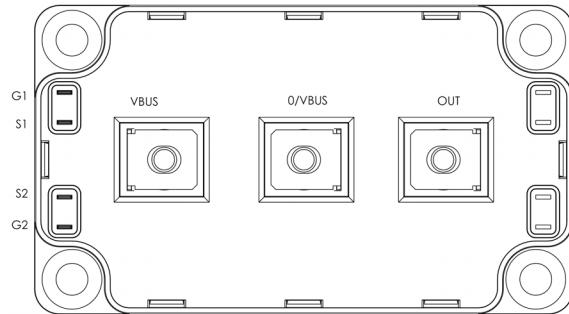
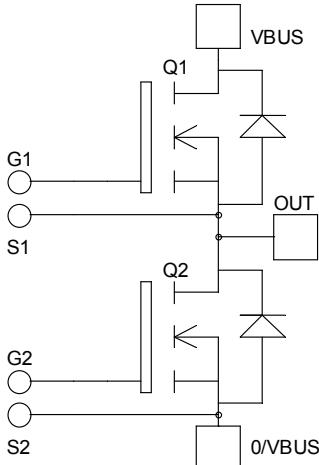


**Phase leg
MOSFET Power Module**

$V_{DSS} = 100V$
 $R_{DSon} = 2.25m\Omega$ typ @ $T_j = 25^\circ C$
 $I_D = 495A$ @ $T_c = 25^\circ C$


Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS V® FREDFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Fast intrinsic diode
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{DSS}	Drain - Source Breakdown Voltage	100	V
I_D	Continuous Drain Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
I_{DM}	Pulsed Drain current	1900	
V_{GS}	Gate - Source Voltage	± 30	V
R_{DSon}	Drain - Source ON Resistance	2.5	$m\Omega$
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	W
I_{AR}	Avalanche current (repetitive and non repetitive)	100	A
E_{AR}	Repetitive Avalanche Energy	50	mJ
E_{AS}	Single Pulse Avalanche Energy	3000	

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0\text{V}$, $V_{DS} = 100\text{V}$	$T_j = 25^\circ\text{C}$			400	μA
		$V_{GS} = 0\text{V}$, $V_{DS} = 80\text{V}$	$T_j = 125^\circ\text{C}$			2000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10\text{V}$, $I_D = 200\text{A}$			2.25	2.5	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10\text{mA}$		2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30\text{ V}$, $V_{DS} = 0\text{V}$				± 400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0\text{V}$ $V_{DS} = 25\text{V}$ $f = 1\text{MHz}$			40		nF
C_{oss}	Output Capacitance				15.7		
C_{rss}	Reverse Transfer Capacitance				5.9		
Q_g	Total gate Charge	$V_{GS} = 10\text{V}$ $V_{Bus} = 50\text{V}$ $I_D = 400\text{A}$			1360		nC
Q_{gs}	Gate – Source Charge				240		
Q_{gd}	Gate – Drain Charge				720		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15\text{V}$ $V_{Bus} = 66\text{V}$ $I_D = 400\text{A}$			160		ns
T_r	Rise Time				240		
$T_{d(off)}$	Turn-off Delay Time				500		
T_f	Fall Time		$R_G = 1.25\Omega$		160		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15\text{V}$, $V_{Bus} = 66\text{V}$ $I_D = 400\text{A}$, $R_G = 1.25\Omega$			2.2		mJ
E_{off}	Turn-off Switching Energy				2.41		
E_{on}	Turn-on Switching Energy		Inductive switching @ 125°C $V_{GS} = 15\text{V}$, $V_{Bus} = 66\text{V}$ $I_D = 400\text{A}$, $R_G = 1.25\Omega$		2.43		mJ
E_{off}	Turn-off Switching Energy				2.56		

Source - Drain diode ratings and characteristics

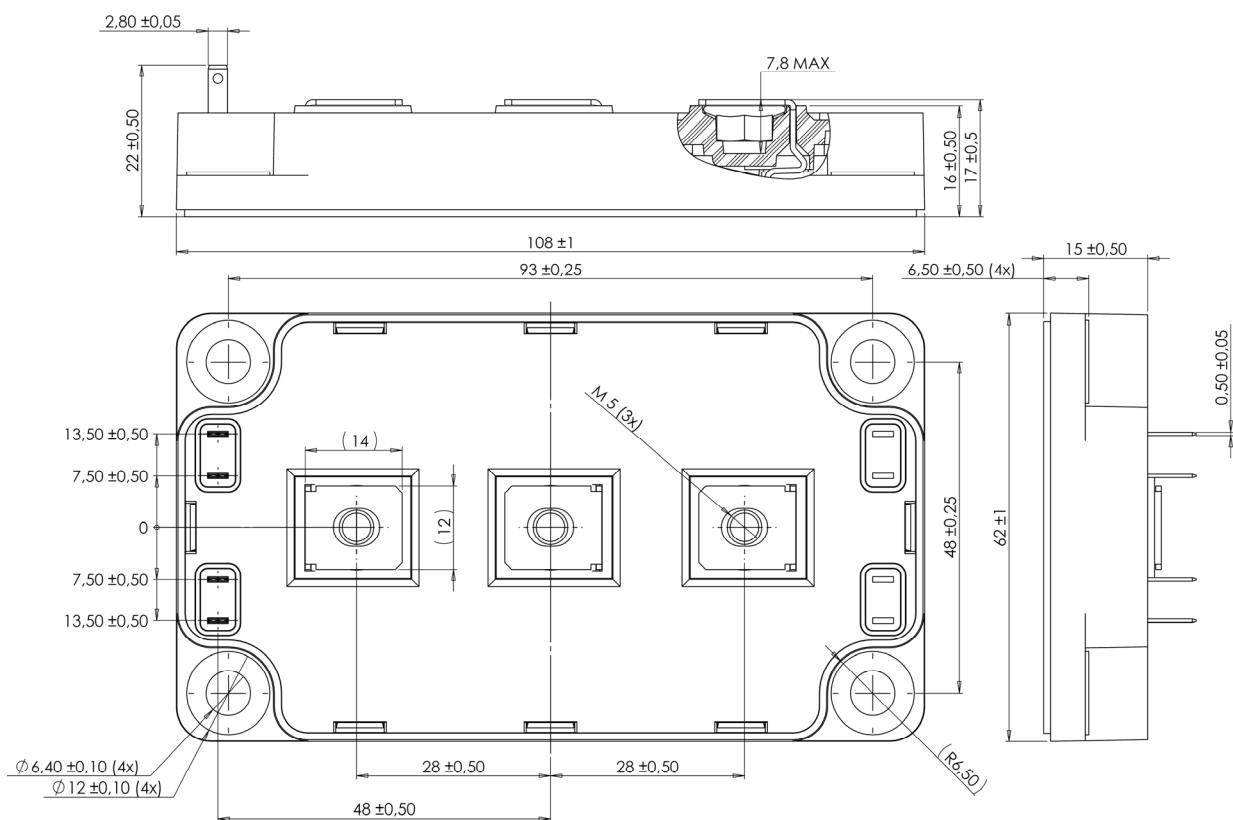
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
I_S	Continuous Source current (Body diode)		$T_c = 25^\circ\text{C}$			495	A	
			$T_c = 80^\circ\text{C}$			370		
V_{SD}	Diode Forward Voltage	$V_{GS} = 0\text{V}$, $I_S = - 400\text{A}$				1.3	V	
dv/dt	Peak Diode Recovery ①					5	V/ns	
t_{rr}	Reverse Recovery Time	$I_S = - 400\text{A}$ $V_R = 66\text{V}$ $dis/dt = 400\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$			190	ns	
			$T_j = 125^\circ\text{C}$			370		
Q_{rr}	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$		1.6		μC	
			$T_j = 125^\circ\text{C}$		6.8			

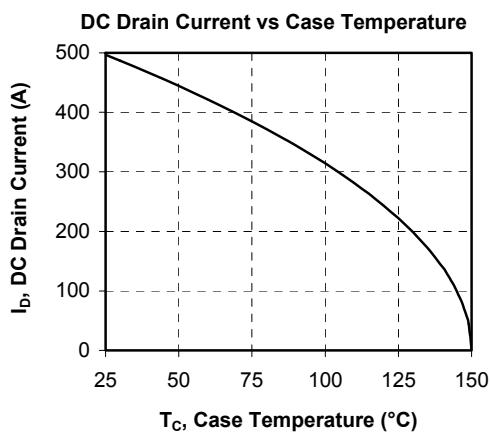
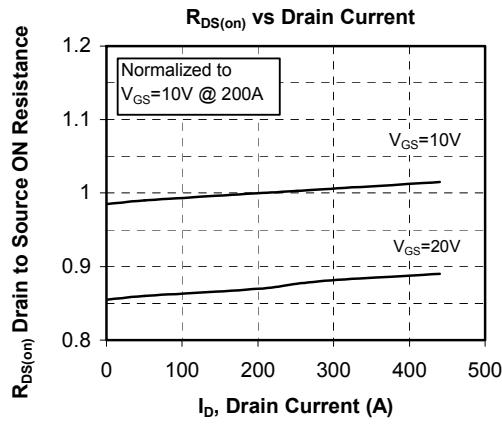
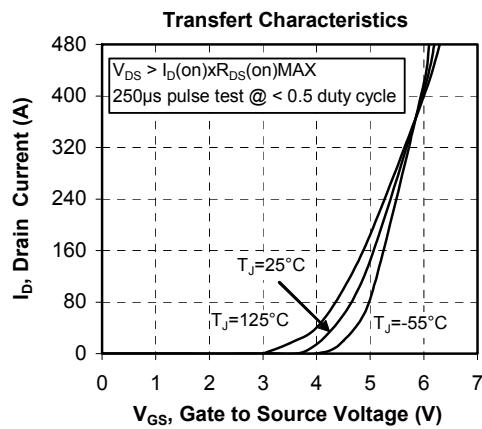
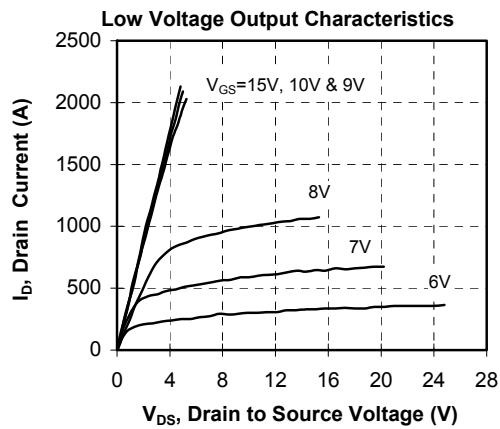
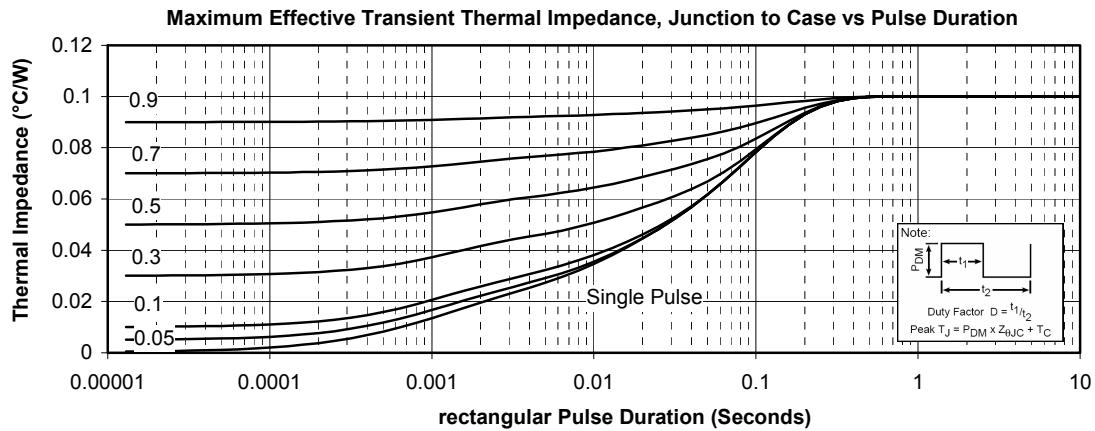
 ① dv/dt numbers reflect the limitations of the circuit rather than the device itself.

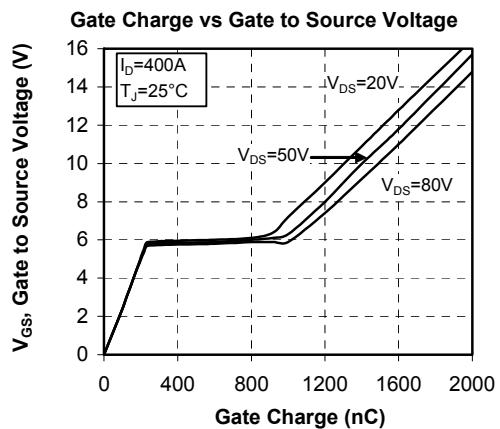
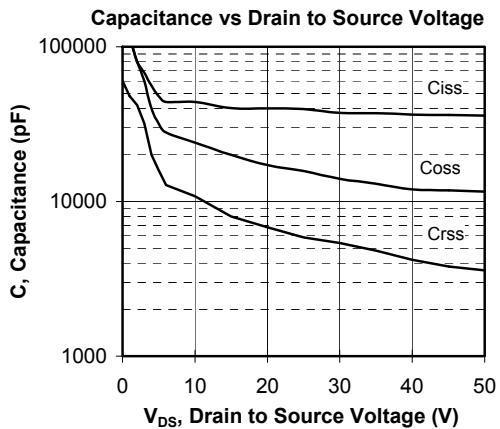
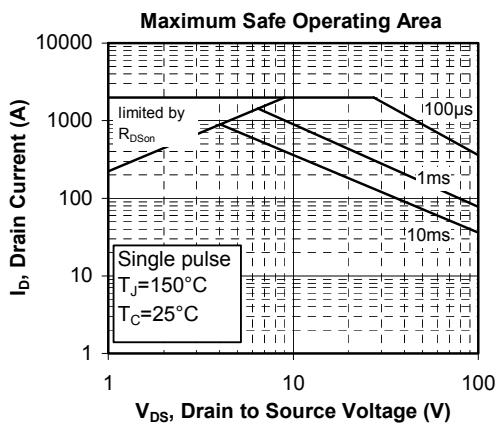
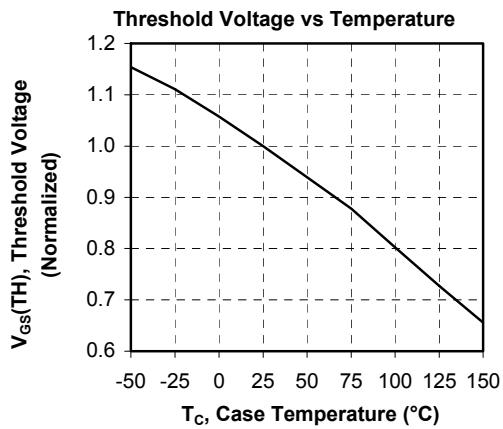
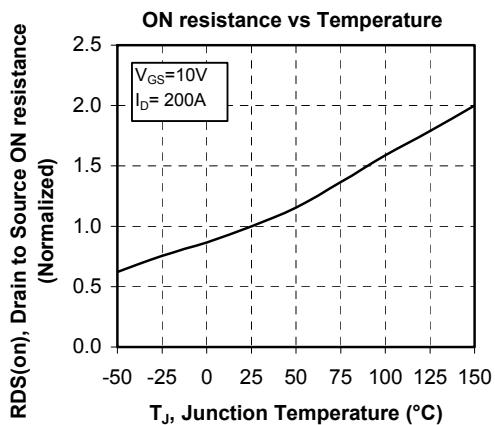
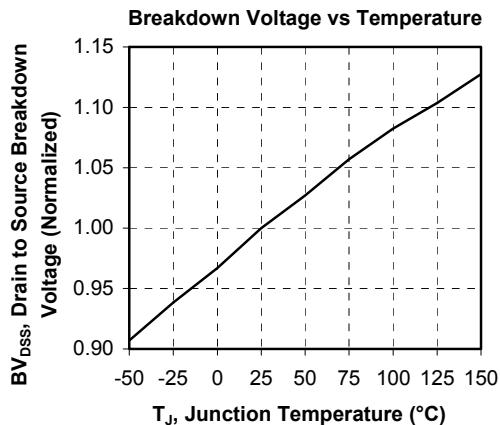
 $I_S \leq - 495\text{A}$ $di/dt \leq 400\text{A}/\mu\text{s}$ $V_R \leq V_{DSS}$ $T_j \leq 150^\circ\text{C}$

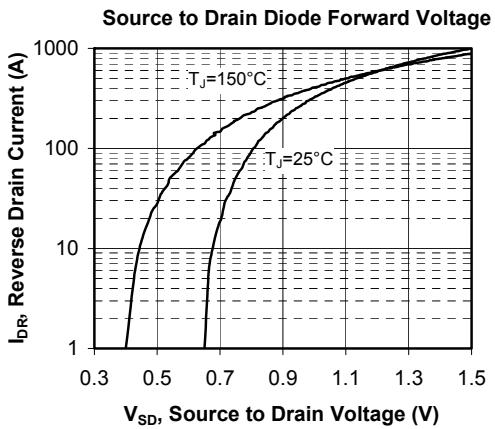
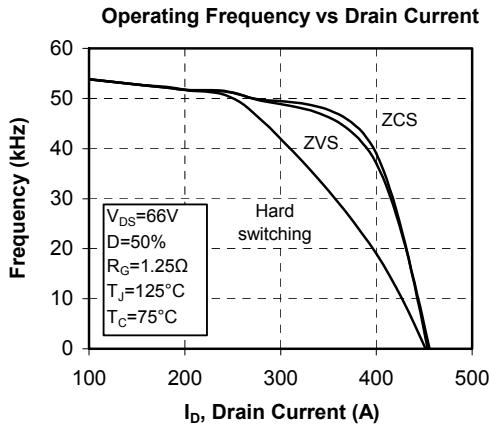
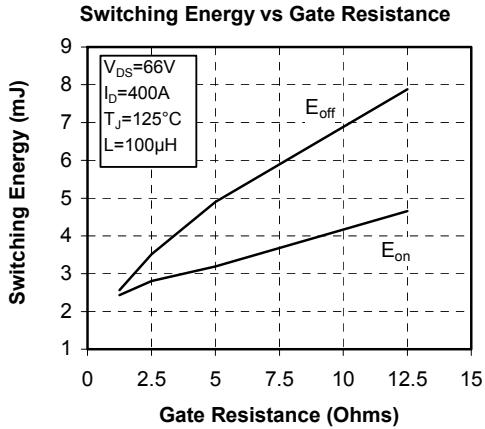
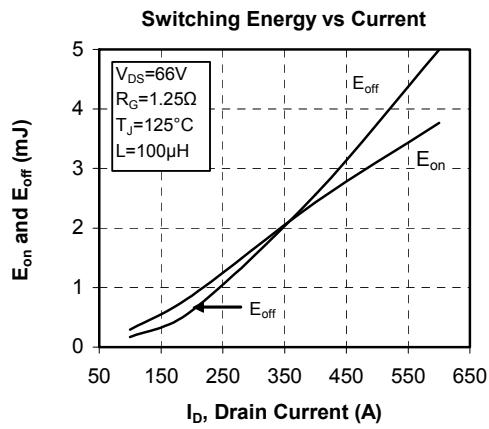
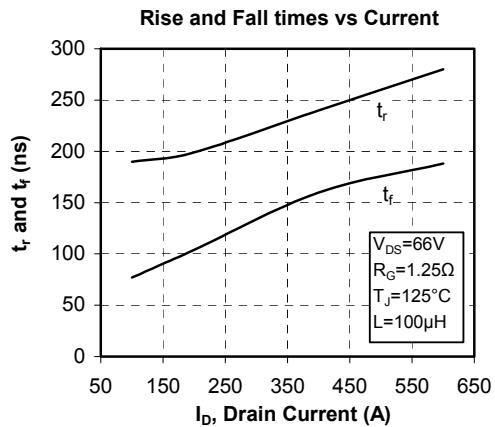
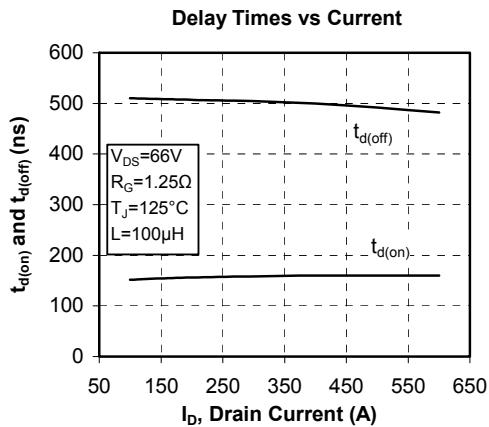
Thermal and package characteristics

Symbol	Characteristic		Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance			0.1		°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz		4000			V
T_J	Operating junction temperature range		-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C
T_C	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink For terminals	M6 M5	3 2	5 3.5	N.m
Wt	Package Weight				300	g

SP6 Package outline (dimensions in mm)

 See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve






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